

MC100LVELT23

3.3V Dual Differential LVPECL to LVTTTL Translator

The MC100LVELT23 is a dual differential LVPECL to LVTTTL translator. Because LVPECL (Positive ECL) levels are used only +3.3 V and ground are required. The small outline 8-lead package and the dual gate design of the LVELT23 makes it ideal for applications which require the translation of a clock and a data signal.

The LVELT23 is available in only the ECL 100K standard. Since there are no LVPECL outputs or an external V_{BB} reference, the LVELT23 does not require both ECL standard versions. The LVPECL inputs are differential. Therefore, the MC100LVELT23 can accept any standard differential LVPECL input referenced from a V_{CC} of +3.3 V.

- 2.0 ns Typical Propagation Delay
- Maximum Frequency > 180 MHz
- Differential LVPECL Inputs
- PECL Mode Operating Range: $V_{CC} = 3.0$ V to 3.8 V with $GND = 0$ V
- 24 mA LVTTTL Outputs
- Flow Through Pinouts
- Internal Pulldown and Pullup Resistors



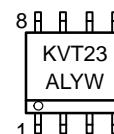
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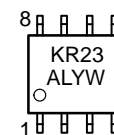
MARKING DIAGRAMS*



SO-8
D SUFFIX
CASE 751



TSSOP-8
DT SUFFIX
CASE 948R



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

Device	Package	Shipping**
MC100LVELT23D	SO-8	98 Units/Rail
MC100LVELT23DR2	SO-8	2500 Units/Reel
MC100LVELT23DT	TSSOP-8	98 Units/Rail
MC100LVELT23DTR2	TSSOP-8	2500 Units/Reel

†For additional tape and reel information, refer to Brochure BRD8011/D.

MC100LVELT23

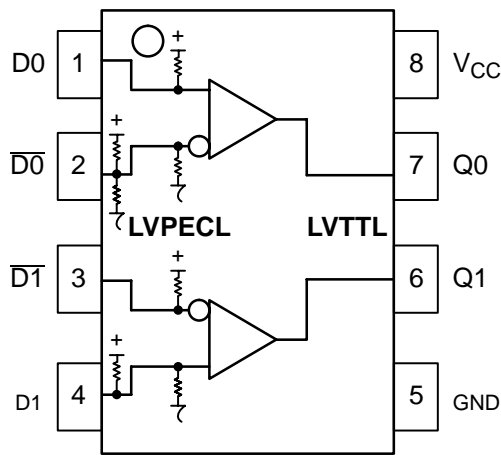


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

PIN DESCRIPTION

PIN	FUNCTION
Qn Dn, \overline{Dn} V _{CC} GND	TTL Outputs PECL Differential Inputs Positive Supply Ground

ATTRIBUTES

Characteristics	Value
Internal Input Pulldown Resistor	75 K Ω
Internal Input Pullup Resistor	37.5 K Ω
ESD Protection	Human Body Model Machine Model > 1.2 kV > 150 V
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	Level 1
Flammability Rating	Oxygen Index: 28 to 34 UL 94 V-0 @ 0.125 in
Transistor Count	91
Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

1. ,Refer to Application Note AND8003/D for additional information.

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MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Power Supply	GND = 0 V		3.8	V
V _I	Input Voltage	GND = 0 V, V _I not more positive than V _{CC}		3.8	V
I _{out}	Output Current	Continuous Surge		50 100	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	SO-8 SO-8	190 130	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	SO-8	41 to 44 ± 5%	°C/W
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	TSSOP-8 TSSOP-8	185 140	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44 ± 5%	°C/W
T _{sol}	Solder Temperature	< 2 to 3 Seconds: 245°C desired		265	°C

2. Maximum Ratings are those values beyond which damage to the device may occur.

LVPECL INPUT DC CHARACTERISTICS V_{CC} = 3.3 V; GND = 0 V (Note 3)

Symbol	Characteristic	-40 °C			25 °C			85 °C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I _{CCH}	Power Supply Current (Outputs set to HIGH)	10	18	25	10	18	25	10	18	25	mA
I _{CCL}	Power Supply Current (Outputs set to LOW)	15	26	33	15	26	33	15	26	33	mA
V _{IH}	Input HIGH Voltage (Note 5)	2135		2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage (Note 5)	1490		1825	1490		1825	1490		1825	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Notes 4 and 5)	2.0		3.3	2.0		3.3	2.0		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μA
I _{IL}	Input LOW Current	D D		0.5			0.5			0.5	μA
		-150			-150			-150			

NOTE: Circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500 lfpm is maintained.

3. All values vary 1:1 with V_{CC}. V_{CC} can vary ±0.3 V.

4. V_{IHCMR} min varies 1:1 with GND, max varies 1:1 with V_{CC}.

5. LVTTTL output R_L = 500 Ω to GND.

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LVTTTL OUTPUT DC CHARACTERISTICS $V_{CC} = 3.3\text{ V}$; GND = 0V (Note 6)

Symbol	Characteristic	-40 °C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output HIGH Voltage ($I_{OH} = -3.0\text{ mA}$) (Note 7)	2.4			2.4			2.4			V
V_{OL}	Output LOW Voltage ($I_{OL} = 24\text{ mA}$) (Note 7)			0.5			0.5			0.5	V
I_{OS}	Output Short Circuit Current	-180		-50	-180		-50	-180		-50	mA

NOTE: Circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

6. All values vary 1:1 with V_{CC} . V_{CC} can vary $\pm 0.3\text{ V}$.

7. LVTTTL output $R_L = 500\ \Omega$ to GND.

AC CHARACTERISTICS $V_{CC} = 3.3\text{ V}$; GND = 0 V (Notes 8, 9)

Symbol	Characteristic	-40 °C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
F_{max}	Maximum Toggle Frequency (Note 10)	180			180			180			MHz
t_{PLH} , t_{PHL}	Propagation Delay to Output Differential	1.0	1.5	2.5	1.0	1.7	2.5	1.0	1.7	2.5	ns
t_{SK++} t_{SK--} t_{SKPP}	Output-to-Output Skew++ Output-to-Output Skew-- Part-to-Part Skew (Note 11)			60 25 500			60 25 500			60 25 500	ps
t_{JITTER}	Random Clock Jitter (RMS)		0.5			0.5			0.5		ps
V_{PP}	Input Voltage Swing (Differential) (Note 12)	200	800	1000	200	800	1000	200	800	1000	mV
t_r t_f	Output Rise/Fall Times (0.8 V - 2.0 V) Q, \bar{Q}	330	600	900	330	600	900	330	650	900	ps

8. All values vary 1:1 with V_{CC} . V_{CC} can vary $\pm 0.3\text{ V}$.

9. LVTTTL output $R_L = 500\ \Omega$ to GND and $C_L = 20\text{ pF}$ to GND. Refer to Figure 2.

10. F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.

11. Skews are measured between outputs under identical conditions.

12. 200 mV input guarantees full logic swing at the output.

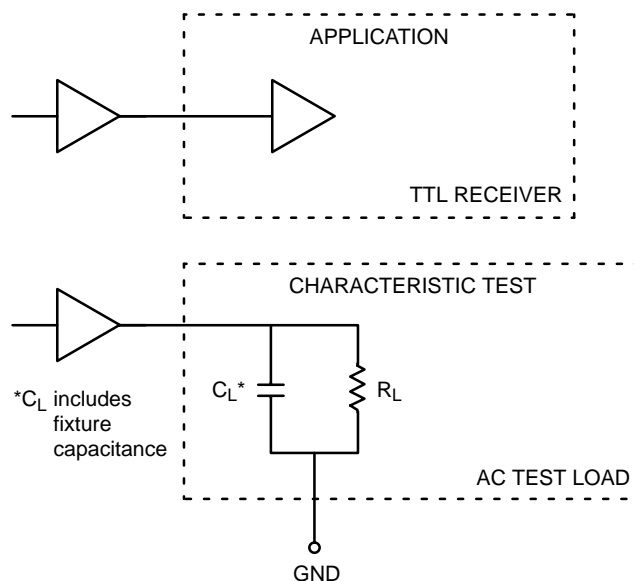


Figure 2. TTL Output Loading Used for Device Evaluation

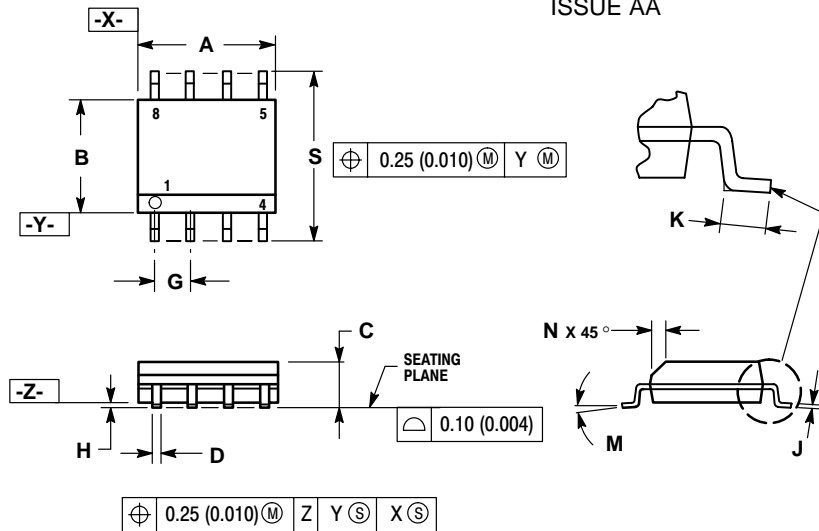
Resource Reference of Application Notes

- AN1404** - ECLinPS Circuit Performance at Non-Standard V_{IH} Levels
- AN1405** - ECL Clock Distribution Techniques
- AN1406** - Designing with PECL (ECL at +5.0 V)
- AN1503** - ECLinPS I/O SPICE Modeling Kit
- AN1504** - Metastability and the ECLinPS Family
- AN1560** - Low Voltage ECLinPS SPICE Modeling Kit
- AN1568** - Interfacing Between LVDS and ECL
- AN1596** - ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
- AN1650** - Using Wire-OR Ties in ECLinPS Designs
- AN1672** - The ECL Translator Guide
- AND8001** - Odd Number Counters Design
- AND8002** - Marking and Date Codes
- AND8020** - Termination of ECL Logic Devices
- AND8090** - AC Characteristics of ECL Devices

MC100LVELT23

PACKAGE DIMENSIONS

SO-8
D SUFFIX
 PLASTIC SOIC PACKAGE
 CASE 751-07
 ISSUE AA



NOTES:

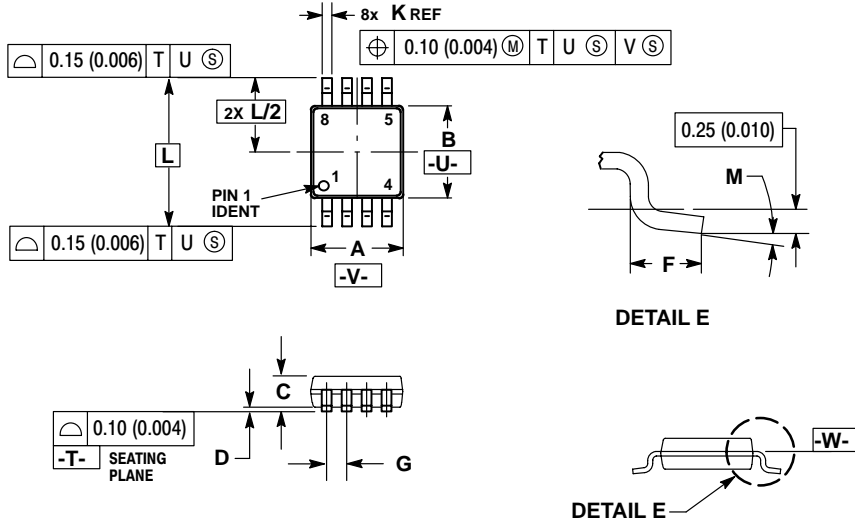
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

MC100LVELT23

PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
 PLASTIC TSSOP PACKAGE
 CASE 948R-02
 ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6°	0°	6°

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